www.vishay.com



01 02 Cathode Anode

#### VS-8ETX06FP-N3

PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub> 8 A						
V <sub>R</sub>	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.4 V					
t <sub>rr</sub> (typ.)	15 ns					
T <sub>J</sub> max.	175 °C					
Package	2L TO-220 FullPAK					
Circuit configuration	Single					

### FEATURES

Hyperfast Rectifier, 8 A FRED Pt<sup>®</sup>

- Hyperfast recovery time
- Benchmark ultra low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- UL pending
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recover time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Repetitive peak reverse voltage	V <sub>RRM</sub>		600	V		
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 106 °C	8			
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	110	А		
Repetitive peak forward current	I <sub>FM</sub>		18			
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25 \ ^{\circ}C$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-	
Forward voltage	V	I <sub>F</sub> = 8 A	-	2.3	3.0	V
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C	-	1.4	1.7	
Poveres lookage ourrept	1	$V_{R} = V_{R}$ rated	-	0.3	50	
Reverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	35	500	μA
Junction capacitance	CT	V <sub>R</sub> = 600 V		17	-	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body - 8.0 -		nH		

Revision: 26-Oct-17

Document Number: 96431

1

Pb-free ROHS COMPLIANT HALOGEN FREE

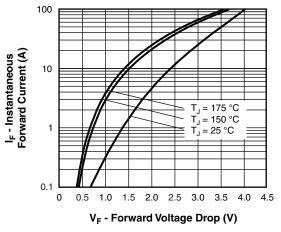


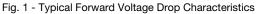
www.vishay.com

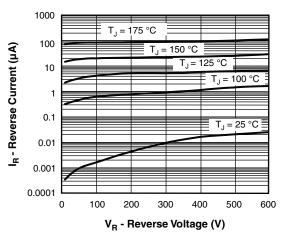
### Vishay Semiconductors

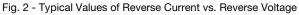
<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_c = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100$	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		15	19	
Reverse recovery time	+	I <sub>F</sub> = 8 A, dI <sub>F</sub> /dt = 100 A/μs, V <sub>R</sub> = 30 V		-	16	24	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	17	-	- ns
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 8 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 390 V	-	40	-	
Peak recovery current		T <sub>J</sub> = 25 °C		-	2.3	-	A
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	4.5	-	
Poweree receivery charge	0	T <sub>J</sub> = 25 °C		-	20	-	nC
Reverse recovery charge Q <sub>rr</sub>		T <sub>J</sub> = 125 °C		-	100	-	
Reverse recovery time	t <sub>rr</sub>		I <sub>F</sub> = 8 A	-	31	-	ns
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	dI <sub>F</sub> /dt = 600 A/µs	-	12	-	Α
Reverse recovery charge	Q <sub>rr</sub>		V <sub>R</sub> = 390 V	-	195	-	nC

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C	
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	3.4	4.3	°C/W	
Thermal resistance, junction-to-ambient per leg	R <sub>thJA</sub>	Typical socket mount	-	-	70		
Thermal resistance, case-to-heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-		
Weight			-	2.0	-	g	
weight			-	0.07	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style 2L TO-220 FullPAK	8ETX06FP				









Document Number: 96431

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

### VS-8ETX06FP-N3

**Vishay Semiconductors** 

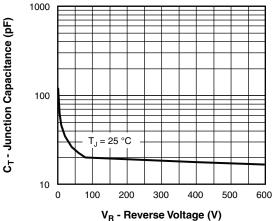
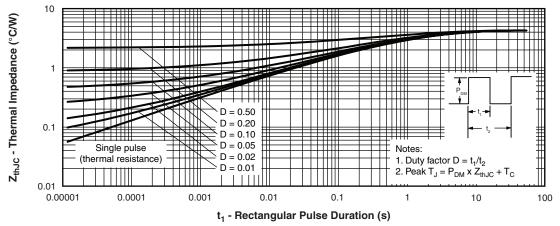
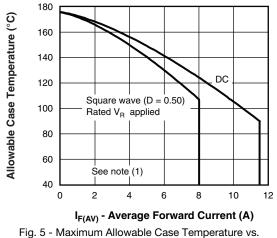


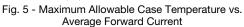
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

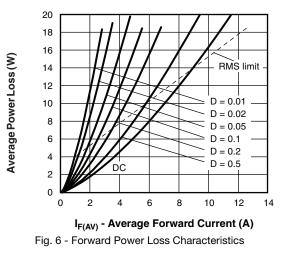






www.vishay.com





#### Note

(1) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \, x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \, x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

Revision: 26-Oct-17

3

Document Number: 96431

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



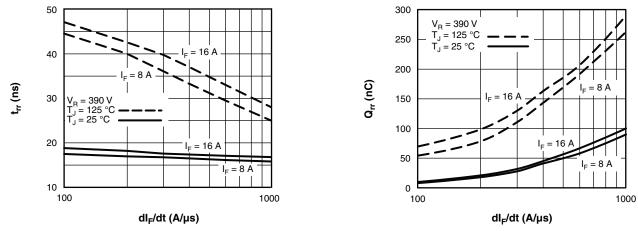


Fig. 7 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

www.vishay.com

SHA



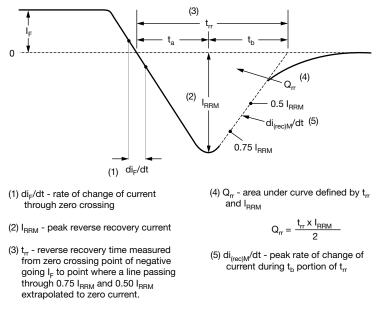


Fig. 9 - Reverse Recovery Waveform and Definitions



#### **ORDERING INFORMATION TABLE**

Device code	vs-	8	Е	т	х	06	FP	-N3
		2	3	4	5	6	7	8
	<b>1</b>	- Visl	nay Sem	nicondu	ctors pro	oduct		
	2 -	- Cur	rent rati	ng (8 =	8 A)			
	3 -	- E=	single					
	4	• T =	TO-220	), D <sup>2</sup> PAł	K (TO-26	63AB)		
	5 -	- X =	hyperfa	ist rectif	ier			
	6	- Volt	age rati	ng (06 =	= 600 V)			
	7 -	FP :	= 2L TO	-220 Fu	IIPAK			
	8 -			ntal digit				
		-N3	= nalog	gen-free	, Rohs-	-compli	ant, and	totally

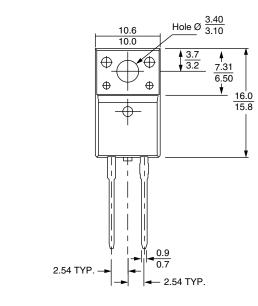
ORDERING INFORMATION (Example)								
PREFERRED P/N	REFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-8ETX06FP-N3	50	1000	Antistatic plastic tube					

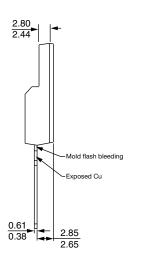
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96157					
Part marking information	www.vishay.com/doc?95392				

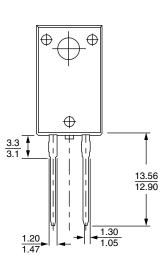


## 2L TO-220 FullPAK

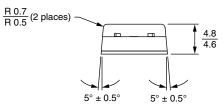
#### **DIMENSIONS** in millimeters







Bottom view





Vishay

### Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Vishay: VS-8ETX06-N3